Z = 4Mo $K\alpha$ radiation

 $\mu = 0.30 \text{ mm}^-$

 $0.40 \times 0.20 \times 0.10 \text{ mm}$

8644 measured reflections

3928 independent reflections

2406 reflections with $I > 2\sigma(I)$

T = 293 K

 $R_{\rm int} = 0.035$

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Tetramethylammonium dimethyl (phenylsulfonylamido)phosphate(1-)

Elizaveta A. Trush,^a* Oleg V. Shishkin,^b Victor A. Trush,^a Irina S. Konovalova^b and Tetyana Yu. Sliva^a

^aNational Taras Shevchenko University, Department of Chemistry, Volodymyrska str. 64, 01601 Kviv, Ukraine, and ^bSTC "Institute for Syngle Crystals", 60 Lenina ave. Khar'kov 61001, Ukraine Correspondence e-mail: elizaveta@univ.kiev.ua

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Key indicators: single-crystal X-ray study; T = 293 K; mean σ (C–C) = 0.004 Å; R factor = 0.032; wR factor = 0.063; data-to-parameter ratio = 19.9.

The title compound, $C_4H_{12}N^+ \cdot C_8H_{11}NO_5PS^-$, was obtained from tetramethylammonium hydroxide and dimethyl(phenylsulfonyl)amidophosphate. The tetramethylammonium cation has a slightly distorted tetrahedral configuration and the N-C bond lengths lie in the range 1.457 (3)-1.492 (3) Å. In the crystal, no classical hydrogen bonds are observed between the cation and the anion.

Related literature

For the synthesis of sulfonylamide derivatives, see: Kirsanov & Shevchenko (1956); Pietraszkiewicz et al. (2002); Trush et al. (2009); Moroz et al. (2009); Shatrava et al. (2010). For the crystal structures of tetramethylammonium compounds, see: Cao et al. (2008); Liu et al. (2004).



Experimental

Crystal data $C_4H_{12}N^+ \cdot C_8H_{11}NO_5PS^-$

 $M_r = 338.36$

Monoclinic, Cc a = 15.2840 (9) Å b = 9.269 (2) Åc = 12.1650 (11) Å $\beta = 98.279 \ (9)^{\circ}$ V = 1705.4 (4) Å³

Data collection

Oxford Diffraction Xcalibur Sapphire3 diffractometer Absorption correction: multi-scan (CrysAlis PRO; Oxford Diffraction, 2010) $T_{\min} = 0.582, \ T_{\max} = 1.000$

Refinement

$R[F^2 > 2\sigma(F^2)] = 0.032$	H-atom parameters constrained
$wR(F^2) = 0.063$	$\Delta \rho_{\rm max} = 0.23 \ {\rm e} \ {\rm \AA}^{-3}$
S = 0.77	$\Delta \rho_{\rm min} = -0.15 \text{ e } \text{\AA}^{-3}$
3928 reflections	Absolute structure: Flack (1983),
197 parameters	1444 Friedel pairs
2 restraints	Flack parameter: 0.05 (6)

Data collection: CrysAlis CCD (Oxford Diffraction, 2006); cell refinement: CrysAlis CCD; data reduction: CrysAlis RED (Oxford Diffraction, 2006); program(s) used to solve structure: SHELXS97 (Sheldrick, 2008); program(s) used to refine structure: SHELXL97 (Sheldrick, 2008); molecular graphics: XP within SHELXTL (Sheldrick, 2008); software used to prepare material for publication: PLATON (Spek, 2009).

Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: WN2457).

References

- Cao, Y., Chen, Y. & Cheng, G. (2008). Acta Cryst. E64, m1546.
- Flack, H. D. (1983). Acta Cryst. A39, 876-881.
- Kirsanov, A. & Shevchenko, V. (1956). Zh. Obshch. Khim. 26, 504-509.
- Liu, F., Sheu, Y., She, J.-J., Chang, Y., Hong, F., Lee, G. & Peng, S. (2004). J. Organomet. Chem. 689, 544-548.
- Moroz, O. V., Trush, V. A., Konovalova, I. S., Shishkin, O. V., Moroz, Y. S., Demeshko, S. & Amirkhanov, V. M. (2009). Polyhedron, 28, 1331-1335.
- Oxford Diffraction (2006). CrysAlis CCD and CrysAlis RED. Oxford Diffraction, Abingdon, England.
- Oxford Diffraction (2010). CrysAlis PRO. Oxford Diffraction Ltd, Yarnton, England.
- Pietraszkiewicz, M., Karpiuk, J. & Staniszewski, K. (2002). J. Alloys Compd, 341, 267-271.
- Shatrava, I. O., Sliva, T. Y., Ovchynnikov, V. A., Konovalova, I. S. & Amirkhanov, V. M. (2010). Acta Cryst. E66, m397-m398.
- Sheldrick, G. M. (2008). Acta Cryst. A64, 112-122.
- Spek, A. L. (2009). Acta Cryst. D65, 148-155.
- Trush, E. A., Trush, V. A., Sliva, T. Y., Konovalova, I. S. & Amirkhanov, V. M. (2009). Acta Cryst. E65, m1231.

supplementary materials

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Tetramethylammonium dimethyl (phenylsulfonylamido)phosphate(1-)

E. A. Trush, O. V. Shishkin, V. A. Trush, I. S. Konovalova and T. Y. Sliva

Comment

To date the coordination chemistry of phosphorylated sulphonylamide ligands has been of great interest (Pietraszkiewicz *et al.*, 2002). Earlier sulfonylamide derivatives of the general type RSO₂NHP(O)(R')₂ and their coordination compounds have been systematically investigated and some results of our study have been already published (Moroz *et al.*, 2009, Shatrava *et al.*, 2010, Trush *et al.* 2009). However, there are no reports of the crystal structure of any alkali- or onic- salts of dimethyl(phenylsulphonyl)amidophosphate (HL). This paper reports the crystal structure of the compound {N(CH₃)₄⁺[C₆H₅SO₂NP(O)(OCH₃)₂]⁻} (Fig. 1).

The highly polar anion contains six potential donor centers and, in spite of this fact, coordinated molecules of water or alcohol have not been detected. (Fig. 2).

The X-ray crystal structure reveals that there are no contacts shorter than 2.44 Å between cation and anion, (the presence of weak C—H···O contacts with the participation of PO and SO₂ oxygens and protons of cation is observed), so the bonding may be considered as mainly ionic.

The dimethyl(phenylsulfonyl)amidophosphatotetramethylammonium salt includes a deprotonated sulphonylamidophosphate anion and cation; the latter has a standard $N(CH_3)_4^+$ -tetrahedral configuration (Fig. 1). The presence of non-equivalent values of C—N bond lengths is a general feature for earlier, structurally investigated tetramethylammonium compounds (Cao *et al.*, 2008; Liu *et al.*, 2004). The geometry of the nearest environment of the phosphorus atom in {L⁻} can be described as a distorted tetrahedron. The bond lengths P1—O3 and P1—N1 have values 1.460 (2) and 1.591 (2) Å, respectively, which are typical of phosphorylated sulfonylamide for compounds with ether-type substituents (Moroz *et al.*, 2009).

The fragments O2—S1—N1—P1 and S1—N1—P1—O5 are practically planar; the values the of corresponding torsion angles are -179.8 (1)° and 163.6 (1)°, respectively; the interplanar angle is 13.2 (2)°. The average deviations of these atoms from these planes do not exceed 0.001 (4) and 0.08 (6) Å, respectively. The phenyl ring is rotated to a considerable extent with respect to the S—N bond, the value of the C2—C1—S1—N1 torsion angle being -36.1 (3)°.

Experimental

The dimethyl(phenylsulfonyl)amidophosphate (HL) was prepared according to the earlier published procedures (Kirsanov *et al.*, 1956). The tetramethylammonium salt { $N(CH_3)_4^+[C_6H_5SO_2NP(O)(OCH_3)_2]^-$ } was obtained by the neutralization reaction: tetramethylammonium hydroxide (0.365 g, 1 mmol of 25% solution) was added dropwise to an equimolar amount (0.265 g, 1 mmol) of HL which was dissolved in 10 ml of isopropanol. The completion of the reaction was checked with phenolphthalein. Colorless crystals suitable for X-ray diffraction were separated. The yield was 0.31 g (92% starting from HL).

Refinement

All H atoms were positioned geometrically and refined using a riding model, with C—H = 0.93-0.96 Å and $U_{iso}(H) = xU_{eq}(C)$, where x = 1.5 for methyl H and 1.2 for all other H atoms. A rotating-group model was applied for the methyl groups. The absolute configuration was determined and the Flack parameter refined to 0.05 (6).

Figures



Fig. 1. The asymmetric unit of dimethyl(phenylsulfonyl)amidophosphato- tetramethylammonium. Displacement ellipsoids are drawn at the 20% probability level; hydrogen atoms are drawn as spheres of arbitrary radius.



Fig. 2. Projection of the structure $\{N(CH_3)_4^+[C_6H_5SO_2NP(O)(OCH_3)_2]^-\}$ on the *ac* plane.

Tetramethylammonium dimethyl (phenylsulfonylamido)phosphate(1-)

Crystal data

$C_4H_{12}N^+ \cdot C_8H_{11}NO_5PS^-$	F(000) = 720
$M_r = 338.36$	$D_{\rm x} = 1.318 {\rm Mg m}^{-3}$
Monoclinic, Cc	Mo <i>K</i> α radiation, $\lambda = 0.71073$ Å
a = 15.2840 (9) Å	Cell parameters from 2883 reflections
b = 9.269 (2) Å	$\theta = 3.0 - 32.2^{\circ}$
c = 12.1650 (11) Å	$\mu = 0.30 \text{ mm}^{-1}$
$\beta = 98.279 \ (9)^{\circ}$	T = 293 K
$V = 1705.4 (4) \text{ Å}^3$	Needle, colourless
Z = 4	$0.40 \times 0.20 \times 0.10 \text{ mm}$

Data collection

Oxford Diffraction Xcalibur Sapphire3 diffractometer	3928 independent reflections
Radiation source: fine-focus sealed tube	2406 reflections with $I > 2\sigma(I)$
graphite	$R_{\rm int} = 0.035$
Detector resolution: 16.1827 pixels mm ⁻¹	$\theta_{\text{max}} = 30.0^{\circ}, \ \theta_{\text{min}} = 3.0^{\circ}$
ω scans	$h = -21 \rightarrow 20$

Absorption correction: multi-scan	k = 12 , 12
(CrysAlis PRO; Oxford Diffraction, 2010)	$k = -12 \rightarrow 13$
$T_{\min} = 0.582, \ T_{\max} = 1.000$	$l = -17 \rightarrow 17$
8644 measured reflections	

Refinement

Refinement on F^2	Hydrogen site location: inferred from neighbouring sites
Least-squares matrix: full	H-atom parameters constrained
$R[F^2 > 2\sigma(F^2)] = 0.032$	$w = 1/[\sigma^2(F_o^2) + (0.0302P)^2]$ where $P = (F_o^2 + 2F_c^2)/3$
$wR(F^2) = 0.063$	$(\Delta/\sigma)_{max} < 0.001$
<i>S</i> = 0.77	$\Delta \rho_{max} = 0.23 \text{ e} \text{ Å}^{-3}$
3928 reflections	$\Delta \rho_{\rm min} = -0.15 \text{ e } \text{\AA}^{-3}$
197 parameters	Extinction correction: <i>SHELXL97</i> (Sheldrick, 2008), $Fc^*=kFc[1+0.001xFc^2\lambda^3/sin(2\theta)]^{-1/4}$
2 restraints	Extinction coefficient: 0.0053 (4)
Primary atom site location: structure-invariant direct methods	Absolute structure: Flack (1983), 1444 Friedel pairs
Secondary atom site location: difference Fourier map	Flack parameter: 0.05 (6)

Special details

Experimental. Analysis found: IR (KBr pellet, cm⁻¹): 1245(v), 1220(vs), 1190(vs), 1060(vs), 1040(δ); 1060 (s, SO₂) and 1190 (s, PO). ¹H NMR (DMSO-d⁶): 3.4 d 6H, ³J_{PH} =11.6 Hz; 7.78 dd (α), 2H; 7.38 m (β + γ), 3H; ³¹P (DMSO-d⁶) -3.27 h, ³J_{HP} = 11.6 Hz.

Geometry. All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R-factor wR and goodness of fit S are based on F^2 , conventional R-factors R are based on F, with F set to zero for negative F^2 . The threshold expression of $F^2 > 2 \text{sigma}(F^2)$ is used only for calculating R-factors(gt) etc. and is not relevant to the choice of reflections for refinement. R-factors based on F^2 are statistically about twice as large as those based on F, and R- factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (A^2)

	x	у	Ζ	$U_{\rm iso}$ */ $U_{\rm eq}$
P1	-0.72846 (3)	-0.17887 (6)	-0.99705 (4)	0.03893 (14)
S1	-0.88898 (4)	-0.24929 (6)	-0.92536 (5)	0.04416 (14)
N1	-0.83352 (11)	-0.18063 (19)	-1.00894 (14)	0.0476 (4)
N2	-0.57619 (11)	-0.5029 (2)	-0.71028 (15)	0.0466 (5)
01	-0.86516 (14)	-0.20683 (19)	-0.81208 (13)	0.0773 (6)
02	-0.98092 (11)	-0.22632 (19)	-0.96904 (16)	0.0740 (5)
O3	-0.67793 (12)	-0.30800 (18)	-0.96015 (16)	0.0681 (5)
O4	-0.69770 (10)	-0.04211 (17)	-0.92503 (14)	0.0618 (4)

O5	-0.70883 (10)	-0.14025 (18)	-1.11691 (12)	0.0586 (4)
C1	-0.87219 (12)	-0.4386 (2)	-0.92758 (17)	0.0373 (5)
C2	-0.86269 (19)	-0.5079 (3)	-1.0247 (2)	0.0609 (6)
H2	-0.8643	-0.4558	-1.0902	0.073*
C3	-0.8507 (2)	-0.6556 (3)	-1.0247 (2)	0.0725 (8)
Н3	-0.8449	-0.7025	-1.0908	0.087*
C4	-0.84735 (16)	-0.7336 (3)	-0.9293 (2)	0.0635 (7)
H4	-0.8390	-0.8329	-0.9298	0.076*
C5	-0.85644 (15)	-0.6633 (3)	-0.8328 (2)	0.0567 (6)
Н5	-0.8545	-0.7152	-0.7671	0.068*
C6	-0.86836 (14)	-0.5174 (3)	-0.83254 (17)	0.0474 (6)
H6	-0.8740	-0.4709	-0.7662	0.057*
C7	-0.60472 (19)	-0.0089 (4)	-0.9058 (3)	0.1007 (12)
H7A	-0.5927	0.0693	-0.9531	0.151*
H7B	-0.5715	-0.0923	-0.9218	0.151*
H7C	-0.5880	0.0184	-0.8295	0.151*
C8	-0.7451 (2)	-0.0104 (3)	-1.1696 (2)	0.0815 (9)
H8B	-0.7178	0.0719	-1.1307	0.122*
H8A	-0.8077	-0.0078	-1.1680	0.122*
H8C	-0.7339	-0.0084	-1.2453	0.122*
С9	-0.62334 (17)	-0.5989 (3)	-0.7979 (2)	0.0644 (7)
H9B	-0.6614	-0.6634	-0.7650	0.097*
H9A	-0.5809	-0.6538	-0.8314	0.097*
H9C	-0.6581	-0.5414	-0.8535	0.097*
C10	-0.52163 (19)	-0.5918 (3)	-0.6247 (2)	0.0697 (7)
H10B	-0.4877	-0.5297	-0.5716	0.105*
H10A	-0.4824	-0.6516	-0.6597	0.105*
H10C	-0.5595	-0.6515	-0.5876	0.105*
C11	-0.51646 (17)	-0.4051 (3)	-0.7616 (2)	0.0689 (7)
H11C	-0.4744	-0.4614	-0.7947	0.103*
H11B	-0.4857	-0.3433	-0.7056	0.103*
H11A	-0.5507	-0.3475	-0.8177	0.103*
C12	-0.63993 (19)	-0.4189 (3)	-0.6587 (2)	0.0727 (8)
H12C	-0.6751	-0.3617	-0.7142	0.109*
H12B	-0.6091	-0.3567	-0.6030	0.109*
H12A	-0.6776	-0.4830	-0.6249	0.109*

Atomic displacement parameters (\AA^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
P1	0.0396 (3)	0.0345 (3)	0.0437 (3)	-0.0002 (3)	0.0096 (2)	0.0012 (3)
S1	0.0473 (3)	0.0415 (3)	0.0467 (3)	-0.0013 (2)	0.0171 (2)	0.0014 (3)
N1	0.0389 (10)	0.0518 (11)	0.0528 (11)	-0.0007 (8)	0.0085 (8)	0.0104 (9)
N2	0.0414 (11)	0.0503 (12)	0.0489 (11)	-0.0025 (9)	0.0087 (8)	0.0038 (9)
O1	0.1328 (17)	0.0603 (11)	0.0427 (10)	-0.0138 (11)	0.0264 (10)	-0.0104 (8)
O2	0.0463 (10)	0.0711 (11)	0.1084 (15)	0.0072 (8)	0.0238 (9)	0.0168 (10)
O3	0.0553 (11)	0.0492 (10)	0.0971 (14)	0.0065 (8)	0.0017 (9)	0.0155 (9)
O4	0.0595 (11)	0.0609 (11)	0.0665 (11)	-0.0170 (8)	0.0142 (8)	-0.0184 (9)

supplementary materials

O5	0.0662 (11)	0.0632 (11)	0.0513 (10)	0.0048 (8)	0.0248 (8)	0.0029 (8)
C1	0.0332 (11)	0.0441 (11)	0.0348 (11)	-0.0091 (8)	0.0064 (8)	-0.0025 (10)
C2	0.0954 (19)	0.0482 (14)	0.0417 (13)	-0.0123 (13)	0.0188 (12)	-0.0044 (11)
C3	0.101 (2)	0.0536 (17)	0.0659 (18)	-0.0144 (14)	0.0224 (15)	-0.0256 (14)
C4	0.0629 (16)	0.0392 (14)	0.089 (2)	-0.0055 (11)	0.0140 (14)	-0.0010 (15)
C5	0.0580 (16)	0.0503 (15)	0.0607 (16)	-0.0055 (11)	0.0047 (12)	0.0146 (12)
C6	0.0552 (14)	0.0525 (14)	0.0344 (13)	-0.0052 (11)	0.0059 (10)	0.0045 (10)
C7	0.073 (2)	0.102 (3)	0.124 (3)	-0.0374 (19)	0.0050 (19)	-0.027 (2)
C8	0.101 (2)	0.081 (2)	0.0664 (18)	0.0027 (17)	0.0261 (16)	0.0275 (15)
C9	0.0523 (15)	0.0679 (16)	0.0732 (17)	-0.0069 (12)	0.0099 (13)	-0.0097 (14)
C10	0.0601 (15)	0.0793 (18)	0.0679 (18)	0.0110 (14)	0.0030 (12)	0.0266 (14)
C11	0.0565 (16)	0.0727 (18)	0.0772 (19)	-0.0160 (13)	0.0083 (13)	0.0213 (14)
C12	0.0573 (15)	0.0800 (19)	0.081 (2)	0.0114 (15)	0.0116 (13)	-0.0142 (16)

Geometric parameters (Å, °)

P1—O3	1.4597 (17)	C5—C6	1.365 (3)
P1—O5	1.5718 (16)	С5—Н5	0.9300
P1—O4	1.5738 (16)	С6—Н6	0.9300
P1—N1	1.5915 (17)	С7—Н7А	0.9600
S1—O1	1.4290 (16)	С7—Н7В	0.9600
S1—O2	1.4447 (16)	С7—Н7С	0.9600
S1—N1	1.5510 (18)	C8—H8B	0.9600
S1—C1	1.774 (2)	C8—H8A	0.9600
N2—C12	1.457 (3)	C8—H8C	0.9600
N2—C10	1.486 (3)	С9—Н9В	0.9600
N2—C11	1.486 (3)	С9—Н9А	0.9600
N2—C9	1.492 (3)	С9—Н9С	0.9600
O4—C7	1.440 (3)	C10—H10B	0.9600
O5—C8	1.437 (3)	C10—H10A	0.9600
C1—C6	1.362 (3)	C10—H10C	0.9600
C1—C2	1.370 (3)	C11—H11C	0.9600
C2—C3	1.381 (4)	C11—H11B	0.9600
С2—Н2	0.9300	C11—H11A	0.9600
C3—C4	1.361 (4)	C12—H12C	0.9600
С3—Н3	0.9300	C12—H12B	0.9600
C4—C5	1.367 (3)	C12—H12A	0.9600
C4—H4	0.9300		
O3—P1—O5	107.99 (10)	С5—С6—Н6	119.4
O3—P1—O4	112.76 (10)	O4—C7—H7A	109.5
O5—P1—O4	104.56 (9)	O4—C7—H7B	109.5
O3—P1—N1	120.12 (10)	Н7А—С7—Н7В	109.5
O5—P1—N1	104.05 (9)	O4—C7—H7C	109.5
O4—P1—N1	105.99 (9)	Н7А—С7—Н7С	109.5
O1—S1—O2	114.42 (12)	H7B—C7—H7C	109.5
O1—S1—N1	115.58 (11)	O5—C8—H8B	109.5
O2—S1—N1	107.03 (10)	O5—C8—H8A	109.5
O1—S1—C1	105.65 (11)	H8B—C8—H8A	109.5
O2—S1—C1	105.98 (10)	O5—C8—H8C	109.5

supplementary materials

N1—S1—C1	107.57 (10)	H8B—C8—H8C	109.5
S1—N1—P1	125.74 (11)	H8A—C8—H8C	109.5
C12—N2—C10	109.7 (2)	N2—C9—H9B	109.5
C12—N2—C11	110.1 (2)	N2—C9—H9A	109.5
C10—N2—C11	108.40 (18)	H9B—C9—H9A	109.5
C12—N2—C9	109.99 (19)	N2—C9—H9C	109.5
C10—N2—C9	109.5 (2)	H9B—C9—H9C	109.5
C11—N2—C9	109.07 (19)	Н9А—С9—Н9С	109.5
C7—O4—P1	118.14 (16)	N2-C10-H10B	109.5
C8—O5—P1	119.47 (16)	N2-C10-H10A	109.5
C6—C1—C2	118.9 (2)	H10B—C10—H10A	109.5
C6-C1-S1	120.41 (16)	N2-C10-H10C	109.5
C2-C1-S1	120.68 (17)	H10B-C10-H10C	109.5
C1—C2—C3	119.7 (2)	H10A—C10—H10C	109.5
С1—С2—Н2	120.2	N2-C11-H11C	109.5
С3—С2—Н2	120.2	N2-C11-H11B	109.5
C4—C3—C2	121.0 (2)	H11C-C11-H11B	109.5
С4—С3—Н3	119.5	N2-C11-H11A	109.5
С2—С3—Н3	119.5	H11C-C11-H11A	109.5
C3—C4—C5	118.9 (2)	H11B—C11—H11A	109.5
С3—С4—Н4	120.6	N2-C12-H12C	109.5
С5—С4—Н4	120.6	N2-C12-H12B	109.5
C6—C5—C4	120.3 (2)	H12C—C12—H12B	109.5
С6—С5—Н5	119.9	N2-C12-H12A	109.5
С4—С5—Н5	119.9	H12C—C12—H12A	109.5
C1—C6—C5	121.2 (2)	H12B—C12—H12A	109.5
С1—С6—Н6	119.4		





Fig. 2

